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DUAL COLOR LED LAMPS



Lead-Free Parts

LURFSDBK2693/R21

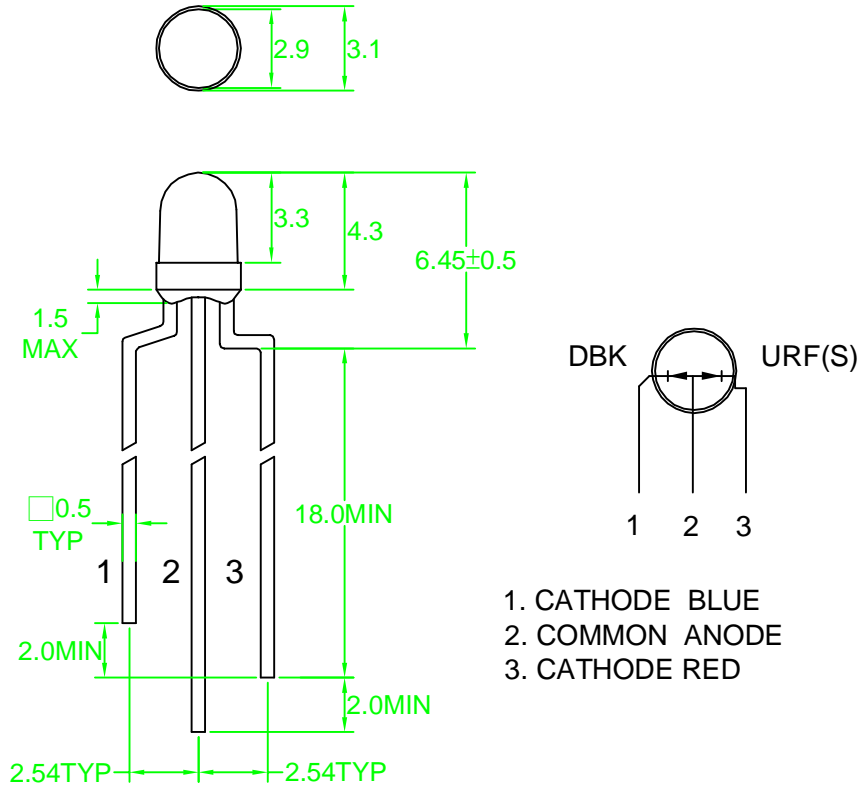
DATA SHEET

DOC. NO : QW0905-LURFSDBK2693/R21

REV. : A

DATE : 28-Oct.- 2015

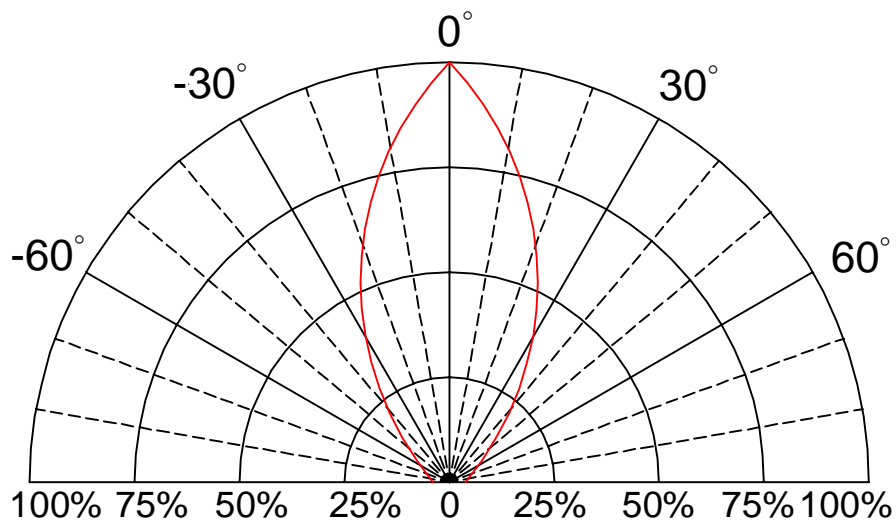
## Package Dimensions



- 1. CATHODE BLUE
- 2. COMMON ANODE
- 3. CATHODE RED

Note : 1.All dimension are in millimeter tolerance is  $\pm 0.25$ mm unless otherwise noted.  
2.Specifications are subject to change without notice.

## Directivity Radiation



Absolute Maximum Ratings at Ta=25 °C

Parameter	Symbol	Ratings		UNIT
		DBK	URF(S)	
Forward Current	IF	30	50	mA
Peak Forward Current Duty 1/10@10KHz	IFP	100	60	mA
Power Dissipation	PD	120	72	mW
Electrostatic Discharge( * )	ESD	500	2000	V
Reverse Current @5V	Ir	50	10	μA
Operating Temperature	Topr	-20 ~ +80	-40 ~ +85	°C
Storage Temperature	Tstg	-30 ~ +100	-40 ~ +100	°C

Typical Electrical & Optical Characteristics (Ta=25 °C)

PART NO	MATERIAL	COLOR		Dominant wave length λ Dnm	Spectral halfwidth Δλ nm	Forward voltage @20mA(V)		Luminous intensity @20mA(mcd)		Viewing angle 2θ 1/2 (deg)
		Emitted	Lens			Min.	Max.	Min.	Typ.	
LURFSDBK2693/R21	AlGaInP	Red	Water Clear	625	20	1.7	2.6	1800	2700	45
	InGaN	Blue		470	30	3.0	4.0	700	1100	45

Note : 1. The forward voltage data did not including ±0.1V testing tolerance.  
2. The luminous intensity data did not including ±15% testing tolerance.

**Brightness Code For Standard LED Lamps****Bin Code**

URF(S) CHIP

Group	Luminous Intensity(mcd) at 20 mA	
	Min.	Max.
A24	1800	2200
A25	2200	2700
A26	2700	3400
A27	3400	4000
A28	4000	5000

**Brightness Code For Standard LED Lamps****Bin Code**

DBK CHIP

Group	Luminous Intensity(mcd) at 20 mA	
	Min.	Max.
A20	700	900
A21	900	1100
A22	1100	1500
A23	1500	1800
A24	1800	2200

**Color Code**

DBK CHIP

Group	Wave length(nm) at 20 mA	
	Min.	Max.
0D	465	468
0C	468	471
0B	471	474

## Typical Electro-Optical Characteristics Curve

### URFS CHIP

Fig.1 Forward current vs. Forward Voltage

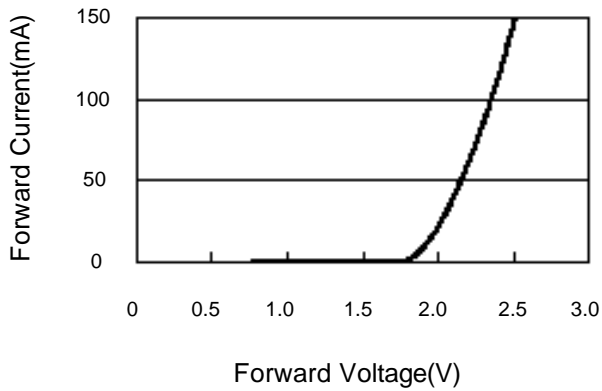


Fig.2 Luminous Intensity vs. Forward Current

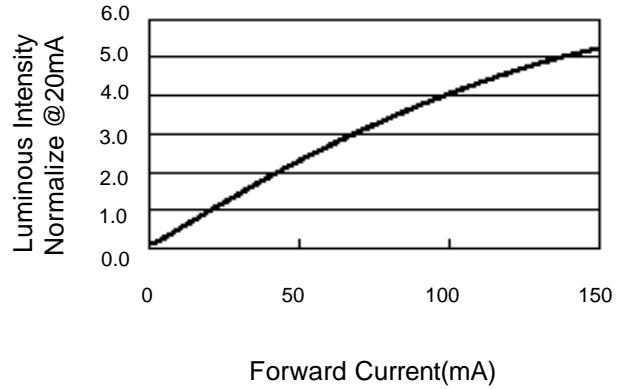


Fig.3 Forward Voltage vs. Temperature

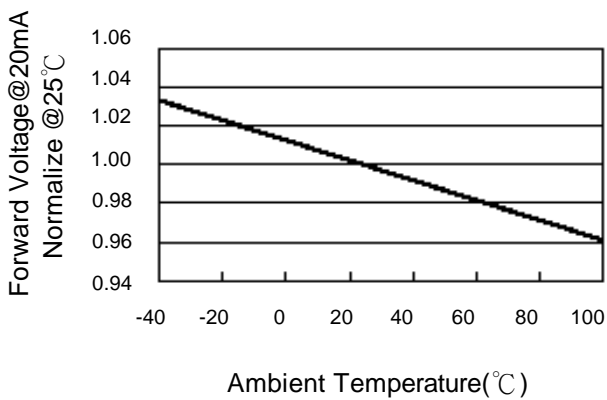


Fig.4 Luminous Intensity vs. Temperature

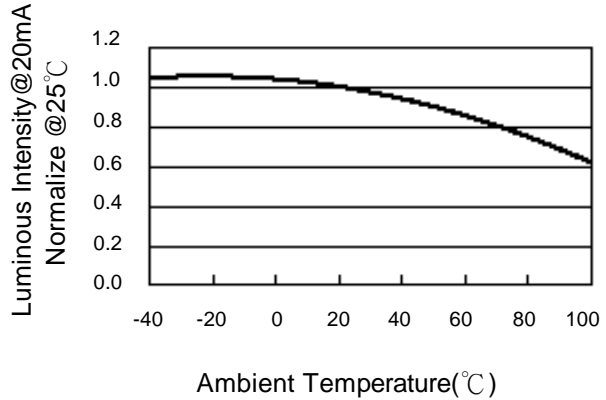
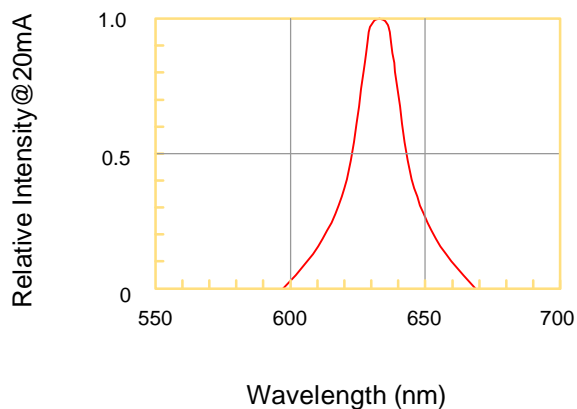


Fig.5 Relative Intensity vs. Wavelength



## Typical Electro-Optical Characteristics Curve

DBK CHIP

Fig.1 Forward current vs. Forward Voltage

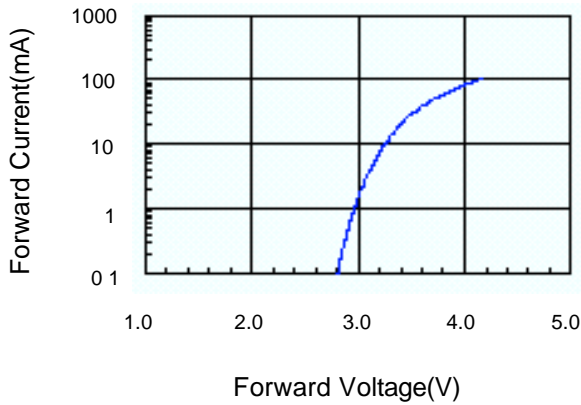


Fig.2 Relative Intensity vs. Forward Current

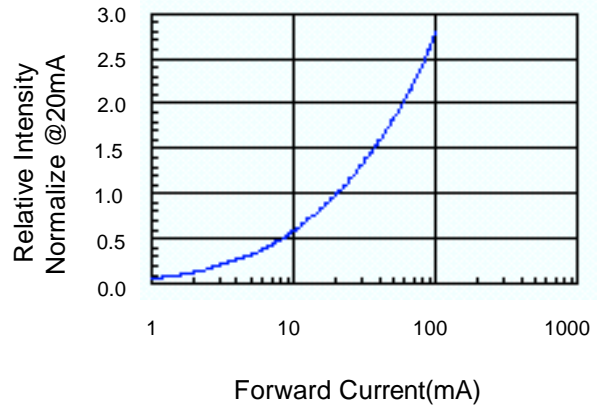


Fig.3 Forward Voltage vs. Temperature

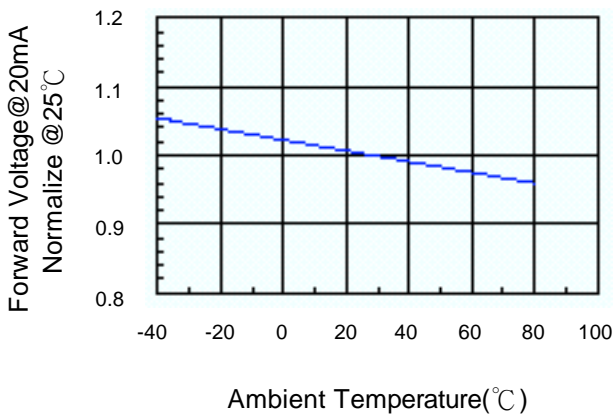


Fig.4 Relative Intensity vs. Temperature

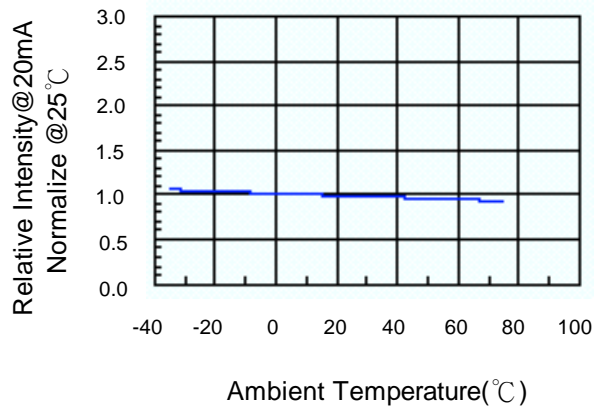


Fig.5 Relative Intensity vs. Wavelength

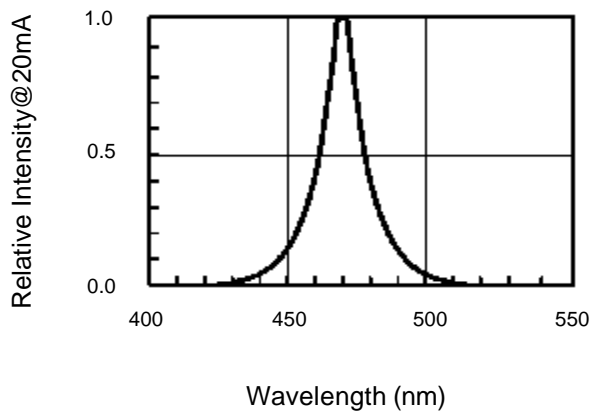


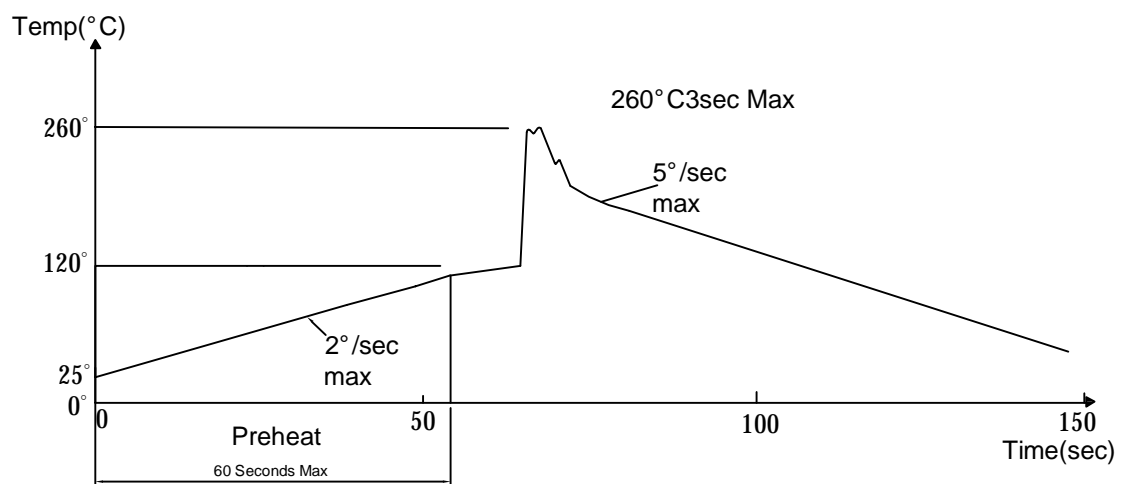
Fig.6 Directivity Radiation

**Soldering Condition(Pb-Free)****1.Iron:**

Soldering Iron:30W Max  
Temperature 350° C Max  
Soldering Time:3 Seconds Max(One time only)  
Distance:2mm Min(From solder joint to body)

**2.Wave Soldering Profile**

Dip Soldering  
Preheat: 120° C Max  
Preheat time: 60seconds Max  
Ramp-up  
2° C/sec(max)  
Ramp-Down:-5° C/sec(max)  
Solder Bath:260° C Max  
Dipping Time:3 seconds Max  
Distance:2mm Min(From solder joint to body)



Note: 1.Wave solder should not be made more than one time.  
2.You can just only select one of the soldering conditions as above.



**Reliability Test:**

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 °C±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 °C±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 °C±5°C 2.RH=90%~95% 3.t=240hrs±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 °C±5°C & -40 °C±5°C (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 °C±5°C 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=245 °C±5°C 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2

## PACKING SPECIFICATION

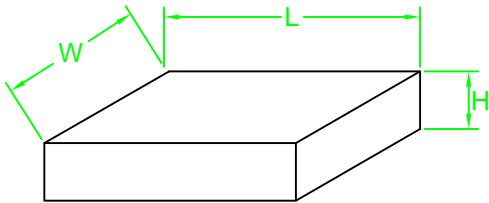
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### 1. 1000PCS / BAG



### 2. 8 BAG / INNER BOX

SIZE : L X W X H 33.5cm X 19cm X 7.5cm



### 3. 12 INNER BOXES / CARTON

SIZE : L X W X H 58.5cm X 34cm X 34cm

